

STI13005-1

High voltage fast-switching NPN power transistor

Preliminary data

Features

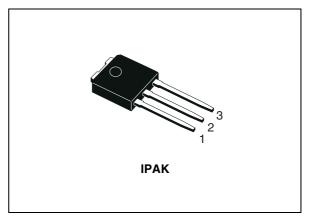
- STI13005-1 is opposite pin out versus standard IPAK package
- High voltage capability
- Low spread of dynamic parameters
- Very high switching speed

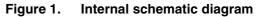
Application

Switch mode power supplies (AC-DC converters)

Description

The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.





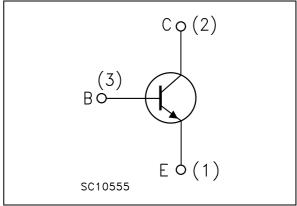


Table 1.	Device summary
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Order code	Marking	Package	Packaging
STI13005-1	113005	IPAK	Tube

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This is preliminary information on a new product now in development or undergoing evaluation. Details are subject to change without notice.

1 Electrical ratings

 Table 2.
 Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CES}	Collector-emitter voltage (V _{BE} = 0)	700	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	400	V
V_{EBO}	Emitter-base voltage (I_{C} = 0; I_{B} = 1.5 A; t_{p} < 10 ms)	V _{(BR)EBO}	V
Ι _C	Collector current	3	Α
I _{CM}	Collector peak current (t _P < 5 ms)	6	Α
Ι _Β	Base current	1.5	Α
I _{BM}	Base peak current (t _P < 5 ms)	3	Α
P _{TOT}	Total dissipation at $T_c = 25 \text{ °C}$	30	W
T _{STG}	Storage temperature	-65 to 150	°C
ТJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thJC}	Thermal resistance junction-case max	4.2	°C/W



2 Electrical characteristics

 T_{case} = 25 °C unless otherwise specified.

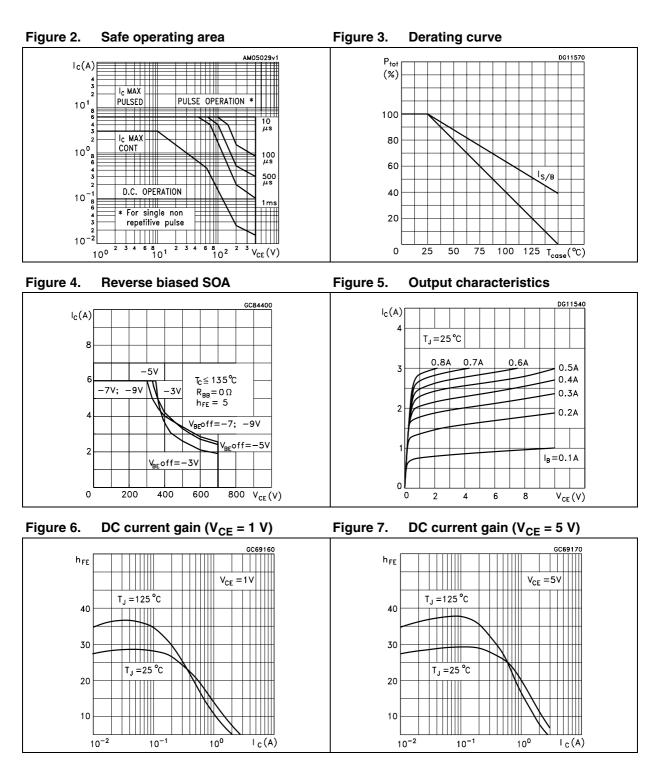
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 700 V V _{CE} = 700 V T _C = 125 °C			1 5	mA mA
I _{CEO}	Collector-cut-off current $(I_B = 0)$	V _{CE} = 400 V			1	mA
V _{(BR)EBO}	Emitter base breakdown voltage $(I_{C} = 0)$	I _E = 10 mA	9		18	v
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage $(I_B = 0)$	I _C = 10 mA	400			v
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$ \begin{array}{ll} I_{C} = 1 A & I_{B} = 200 \text{ mA} \\ I_{C} = 2 A & I_{B} = 500 \text{ mA} \\ I_{C} = 3 A & I_{B} = 750 \text{ mA} \end{array} $			0.5 0.6 5	V V V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	$I_{C} = 1A \qquad I_{B} = 200 \text{ mA}$ $I_{C} = 2A \qquad I_{B} = 500 \text{ mA}$			1.2 1.6	V V
h _{FE} ⁽¹⁾	DC current gain	$ \begin{array}{ll} I_{C} = 500 \; \mu A & V_{CE} = 2 \; V \\ I_{C} = 425 \; m A & V_{CE} = 2 \; V \\ I_{C} = 1 \; A & V_{CE} = 5 \; V \\ I_{C} = 2 \; A & V_{CE} = 5 \; V \end{array} $	15 24 10 8		30 24	
t _s t _f	Resistive load Storage time Fall time	$\label{eq:loss} \begin{array}{ll} I_{C} = 2 \mbox{ A} & V_{CC} = 125 \mbox{ V} \\ I_{B1} = -I_{B2} = 400 \mbox{ mA} \\ t_{p} = 30 \mu s \end{array}$		1.65 260		µs ns
t _s t _f	Inductive load Storage time Fall time	$ I_C = 1 \ A \qquad V_{clamp} = 300 \ V \\ I_{B1} = 200 \ mA \ V_{BE(off)} = -5 \ V \\ L = 50 \ mH \qquad R_{BB} = 0 $		0.8 150		µs ns

 Table 4.
 Electrical characteristics

1. Pulse test: pulse duration \leq 300 µs, duty cycle \leq 2 %



2.1 Electrical characteristics (curves)





 $I_{C}(A)$

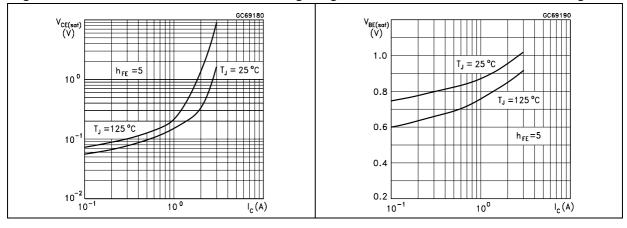
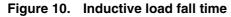


Figure 8. Collector-emitter saturation voltage Figure 9. **Base-emitter saturation voltage**



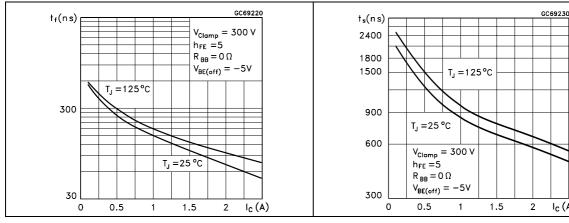
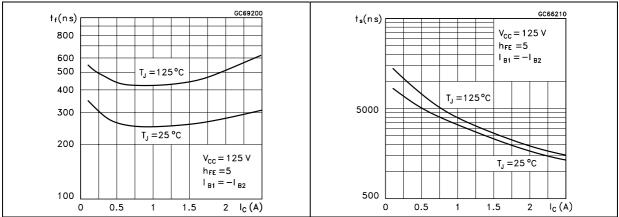


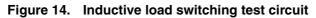


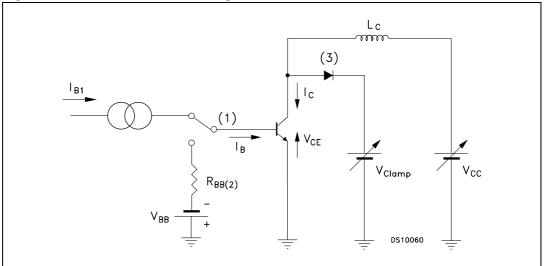


Figure 11. Inductive load storage time



3 Test circuits



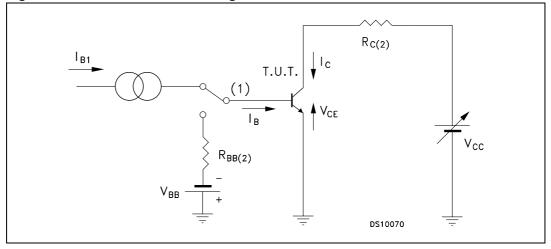


1) Fast electronic switch

2) Non-inductive resistor

3) Fast recovery rectifier

Figure 15. Resistive load switching test circuit



1) Fast electronic switch

2) Non-inductive resistor



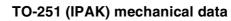
4 Package mechanical data

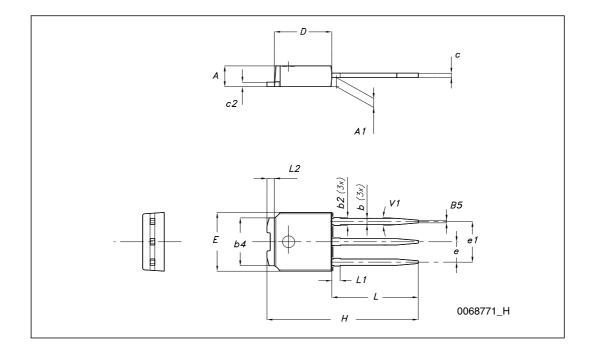
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им. —		mm.	
	min.	typ	max.
۸ (2.20		2.40
A1	0.90		1.10
b	0.64		0.90
b2			0.95
b4	5.20		5.40
с	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
E	6.40		6.60
е		2.28	
e1	4.40		4.60
н		16.10	
L	9.00		9.40
(L1)	0.80		1.20
L2		0.80	
V1		10 °	







5 Revision history

Table 5.Document revision history

Date	Revision	Changes
18-Feb-2010	1	First release.



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